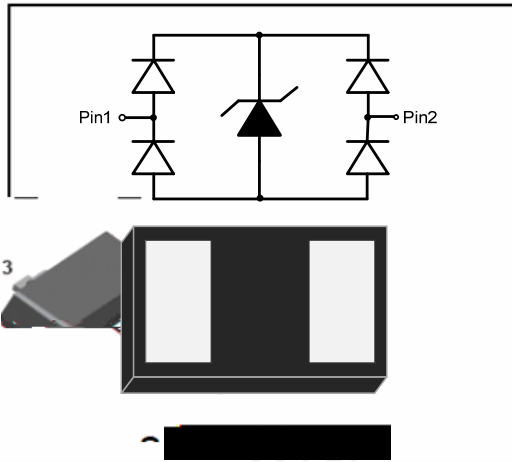


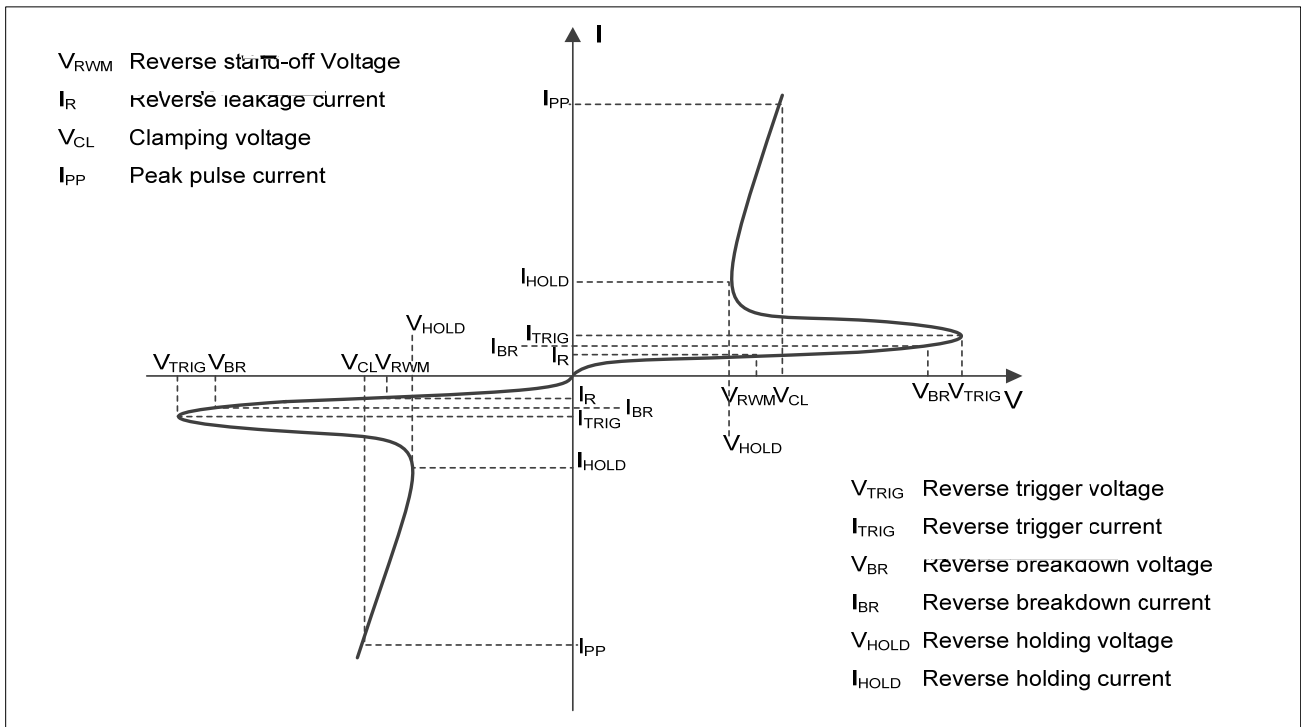
1- Line, Bi-directional, Ultra-low Capacitance Transient Voltage Suppressor



Features

- Stand-off voltage: 3.3V Max
- Transient protection for each line according to IEC61000-4-2(ESD): $\pm 15\text{kV}$ (contact)
- IEC61000-4-5(surge): 8A (8/20 μs)
- Ultra-low capacitance: $C_J = 0.8\text{pF}$ typ
- Ultra-low leakage current: $I_R < 1\text{nA}$ typ.
- Low clamping voltage: $V_{CL} = 6.3\text{V}$ typ. @ $I_{PP} = 16\text{A}$ (TLP)
- MSolid-state SMDFN1006-2L

Terminals: Tin plated leads, solderable per J-STD-002 and JESD22-B102





ESDSL3V3LBA

Maximum Ratings

PARAMETER	SYMBOL	Rating	UNIT
Peak pulse power ($t_p = 8/20\mu s$)	P_{pk}	68	W
Peak pulse current ($t_p = 8/20\mu s$)	I_{pp}	7	A
ESD according to IEC61000-4-2 air discharge	V_{ESD}	± 30	KV
ESD according to IEC61000-4-2 contact discharge		± 30	KV
Junction temperature	T_J	125	$^{\circ}C$
Operating temperature	T_{OP}	-40~85	$^{\circ}C$
Storage temperature	T_{STG}	-55~150	$^{\circ}C$

Electrical Characteristics $T_a=25$ Unless otherwise specified

PARAMETER	Symbol	UNIT	Conditions	Min	Typ	Max
Reverse maximum working voltage	V_{RWM}	V				3.3
Reverse leakage current	I_R	nA	$V_{RWM} = 3.3V$			50
Reverse breakdown voltage	V_{BR}	V	$I_{BR} = 1mA$	7.0	10.0	
Clamping voltage ¹⁾	V_{CL}	V	$I_{PP} = 16A, t_p = 100ns$		6.3	
Dynamic resistance ¹⁾	R_{DYN}				0.17	
Clamping voltage ²⁾	V_{CL}	V	$V_{ESD} = 8kV$		6.3	
Clamping voltage ³⁾	V_{CL}	V	$I_{PP} = 1A, t_p = 8/20\mu s$		3.2	4.5
		V	$I_{PP} = 7A, t_p = 8/20\mu s$		6.5	8.5
Junction capacitance	C_J	pF	$V_R = 0V, f = 1MHz$		0.8	1

(1). TLP parameter: $Z_0 = 50$, $t_p = 100ns$, $t_r = 2ns$, averaging window from 60ns to 80ns. R_{DYN} is calculated from 4A to 16A.

(2). Contact discharge mode, according to IEC61000-4-2.

(3). Non-repetitive current pulse, according to IEC61000-4-5.

Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(mg)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
ESDSL3V3LBA	Approximate 0.9	10000	100000	400000	Tape&reel



ESDSL3V3LBA

Characteristics (Typical)

8/20 μs waveform per IEC61000 4 5

Contact discharge current waveform per IEC61000 4 2

Clamping voltage vs. Peak pulse current

Capacitance vs. Reverse voltage

Non repetitive peak pulse power vs. Pulse time



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ESD damping
(+8kV contact discharge per IEC61000 4 2)

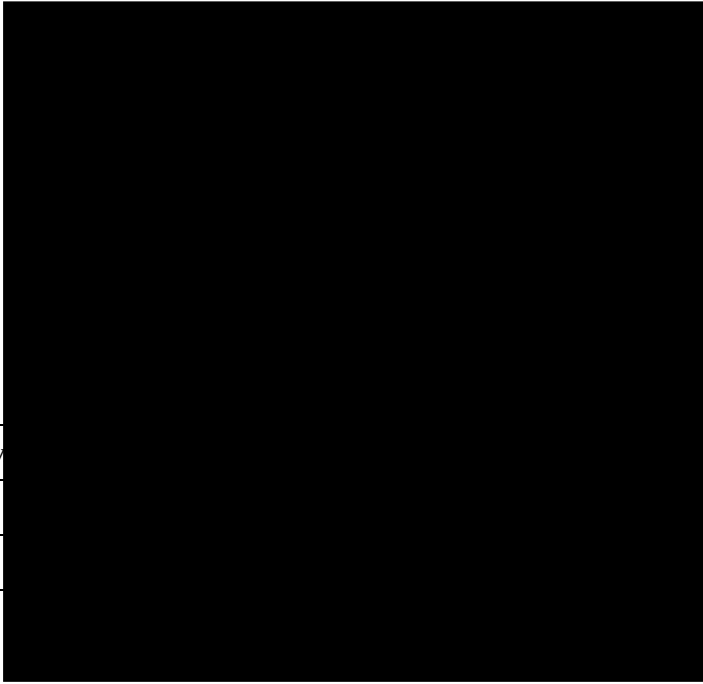
ESD damping
(-8kV contact discharge per IEC61000 4 2)

TLP Measurement

Outline Dimensions



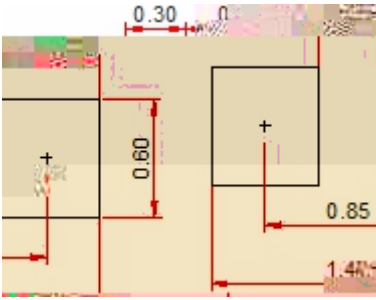
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Recommend land pattern (Unit:mm)



Notes:
This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met



ESDSL3V3LBA

Disclaimer

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